# Switching diode

# **1SS400**

#### Applications

High speed switching

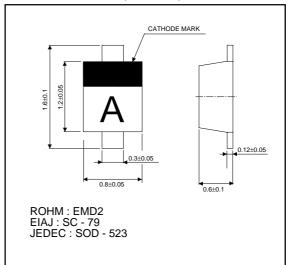
#### Features

- 1) Extremely small surface mounting type.(EMD2)
- 2) High Speed.(tr=1.2ns Typ.)
- 3) High reliability.

#### ●Construction

Silicon epitaxial planar

# ●External dimensions (Units : mm)



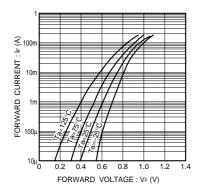
### ● Absolute maximum ratings (Ta = 25°C)

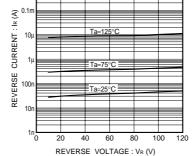
Parameter	Symbol	Limits	Unit
Peak reverse voltage	Vrm	90	V
DC reverse voltage	VR	80	V
Peak forward current	Iғм	225	mA
Mean rectifying current	lo	100	mA
Surge current (1s)	Isurge	500	mA
Junction temperature	Tj	125	°C
Storage temperature	Tstg	−55 ~ +125	°C

# ●Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	VF	_	-	1.2	V	I <sub>F</sub> =100mA
Reverse current	lR	-	-	0.1	μΑ	V <sub>R</sub> =80V
Capacitance between terminals	Ст	-	0.72	3.0	pF	V <sub>R</sub> =0.5V , f=1MHz
Reverse recovery time	trr	-	-	4	ns	$V_R=6V$ , $I_F=10mA$ , $R_L=100\Omega$

### ●Electrical characteristic curves (Ta = 25°C)





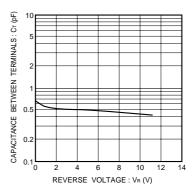
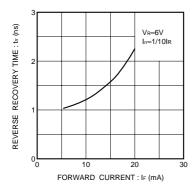
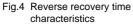


Fig.1 Forward characteristics

Fig.2 Reverse characteristics

Fig.3 Capacitance between terminals





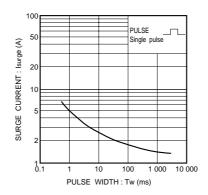


Fig.5 Surge current characteristics

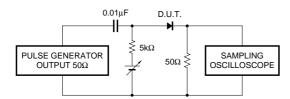


Fig.6 Reverse recovery time (t<sub>rr</sub>) measurement circuit

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